

NSBA123JDXV6T5G

NSBA123JDXV6T5G Information

Novembersener.com	 NSBA123JDXV6T5G ON Semiconductor Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2PNP PREBIAS 0.5W SOT563 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

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NSBA123JDXV6T5G Specifications

Manufacturer Part Number NSBA123JDXV6T5G Manufacturer ON Semiconductor Category Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased Transistors - Bipolar (BJT) - Arrays, Pre-Biased Package SOT-563, SOT-666 Series - Transistor Type 2 PNP - Pre-Biased (Dual) Current - Collector (Ic) (Max) 100mA Voltage - Collector Emitter Breakdown (Max) 50V Resistor - Base (R1) (Ohms) 2.2k Resistor - Emitter Base (R2) (Ohms) 47k DC Current Gain (hFE) (Min) @ Ic, Vce 80 @ 5mA, 10V Vec Saturation (Max) @ Ib, Ic 250mV @ 300µA, 10mA Current - Collector Cutoff (Max) 500nA Frequency - Transition - Power - Max 500mW Mounting Type Surface Mount Package / Case SOT-563, SOT-666 Supplier Device Package SOT-563		
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - Arrays, Pre-BiasedPackageSOT-563, SOT-666Series-Transistor Type2 PNP - Pre-Biased (Dual)Current - Collector (Lc) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Lc, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Lc250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Manufacturer Part Number	NSBA123JDXV6T5G
ImpersonanceTransistors - Bipolar (BJT) - Arrays, Pre-BiasedPackageSOT-563, SOT-666Series-Transistor Type2 PNP - Pre-Biased (Dual)Current - Collector (Ic) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Manufacturer	ON Semiconductor
PackageSOT-563, SOT-666Series-Transistor Type2 PNP - Pre-Biased (Dual)Current - Collector (Ic) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Suppler Device PackageSOT-563	Category	Discrete Semiconductor Products
Series-Transistor Type2 PNP - Pre-Biased (Dual)Current - Collector (Ic) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Base (R2) (Ohms)47kDC Current Gain (hFE) (Min @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563		Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Transistor Type2 PNP - Pre-Biased (Dual)Current - Collector (Lo) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Package	SOT-563, SOT-666
Current - Collector (Ic) (Max)100mAVoltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Series	-
Voltage - Collector Emitter Breakdown (Max)50VResistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseS0T-563, SOT-666Supplier Device PackageSOT-563	Transistor Type	2 PNP - Pre-Biased (Dual)
Resistor - Base (R1) (Ohms)2.2kResistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Current - Collector (Ic) (Max)	100mA
Resistor - Emitter Base (R2) (Ohms)47kDC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Voltage - Collector Emitter Breakdown (Max)	50V
DC Current Gain (hFE) (Min) @ Ic, Vce80 @ 5mA, 10VVce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Resistor - Base (R1) (Ohms)	2.2k
Vce Saturation (Max) @ Ib, Ic250mV @ 300µA, 10mACurrent - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Resistor - Emitter Base (R2) (Ohms)	47k
Current - Collector Cutoff (Max)500nAFrequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 5mA, 10V
Frequency - Transition-Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Vce Saturation (Max) @ Ib, Ic	250mV @ 300μA, 10mA
Power - Max500mWMounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Current - Collector Cutoff (Max)	500nA
Mounting TypeSurface MountPackage / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Frequency - Transition	-
Package / CaseSOT-563, SOT-666Supplier Device PackageSOT-563	Power - Max	500mW
Supplier Device Package SOT-563	Mounting Type	Surface Mount
	Package / Case	SOT-563, SOT-666
Report errors?	Supplier Device Package	SOT-563
		Report errors?

NSBA123JDXV6T5G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NSBA123JDXV6T5G Payment Methods





If you have any question about NSBA123JDXV6T5G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com